

May 2014

### FDD6N25

# N-Channel UniFET<sup>TM</sup> MOSFET 250 V, 4.4 A, 1.1 $\Omega$

#### **Features**

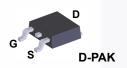
- $R_{DS(on)}$  = 1.1  $\Omega$  (Max.) @  $V_{GS}$  = 10 V,  $I_D$  = 2.2 A
- Low Gate Charge (Typ. 4.5 nC)
- Low C<sub>rss</sub> (Typ. 5 pF)
- 100% Avalanche Tested

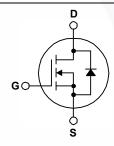
### **Applications**

- LCD/LED/PDP TV
- · Consumer Appliances
- Lighting
- · Uninterruptible Power Supply
- · AC-DC Power Supply

### **Description**

UniFET<sup>TM</sup> MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts





### **Absolute Maximum Ratings** T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FDD6N25TM	Unit
V <sub>DSS</sub>	Drain-Source Voltage			250	V
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 25°C) - Continuous (T <sub>C</sub> = 100°C)		4.4 2.6	A A
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	18	Α
V <sub>GSS</sub>	Gate-Source voltage			±30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	45	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1)	4.4	Α
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	5	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5	V/ns
$P_{D}$	Power Dissipation	(T <sub>C</sub> = 25°C) - Derate Above 25°C		50 0.4	W/°C
T <sub>J,</sub> T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C

#### **Thermal Characteristics**

Symbol	Parameter	FDD6N25TM	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.		C/VV

### **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDD6N25TM	FDD6N25	DPAK	Tape and Reel	330 mm	16 mm	2500 units

### **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
Off Charac	teristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	250			V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250 μA, Referenced to 25°C		0.25		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 250 V, V <sub>GS</sub> = 0 V V <sub>DS</sub> = 200 V, T <sub>C</sub> = 125°C			1 10	μA μA
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	V <sub>GS</sub> = -30 V, V <sub>DS</sub> = 0 V			-100	nA
On Charac	teristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	3.0		5.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2.2 A		0.9	1.1	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 40 V, I <sub>D</sub> = 2.2 A	-	5.5		S
Dynamic C	haracteristics				•	
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V,		194	250	pF
C <sub>oss</sub>	Output Capacitance	f = 1 MHz		38	50	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			5	8	pF
Switching	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> = 125 V, I <sub>D</sub> = 6 A,		10	30	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{GS}$ = 10 V, $R_G$ = 25 $\Omega$		25	60	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			7	24	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)		12	34	ns
Qg	Total Gate Charge	V <sub>DS</sub> = 200 V, I <sub>D</sub> = 6 A,	/	4.5	6	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = 10 V		1.5		nC
Q <sub>gd</sub>	Gate-Drain Charge	(Note 4)	/	1.8		nC
Drain-Sour	rce Diode Characteristics and Maximur	n Ratings				
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				4.4	Α
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current				18	Α
$V_{SD}$	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 4.4 A	-		1.4	V
t <sub>rr</sub>	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{S} = 6 \text{ A},$		145		ns
Q <sub>rr</sub>	Reverse Recovery Charge	dl <sub>F</sub> /dt =100 A/μs		0.55		μС

#### Notes

<sup>1.</sup> Repetitive rating: pulse-width limited by maximum junction temperature.

<sup>2.</sup> L = 3.7 mH, I  $_{AS}$  = 4.4 A, V  $_{DD}$  = 50 V, R  $_{G}$  = 25  $\Omega,$  starting T  $_{J}$  = 25  $^{\circ}C.$ 

<sup>3.</sup>  $I_{SD} \le 4.4$  A, di/dt  $\le 200$  A/ $\mu$ s,  $V_{DD} \le BV_{DSS}$ , starting  $T_J$  = 25°C.

<sup>4.</sup> Essentially independent of operating temperature typical characteristics.

### **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

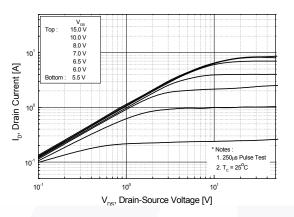


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

**Figure 2. Transfer Characteristics** 

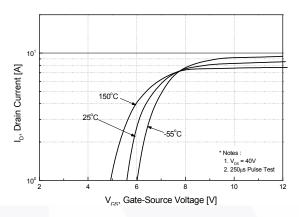


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

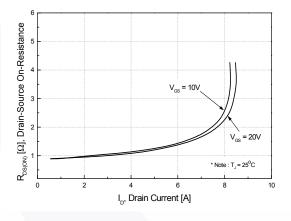
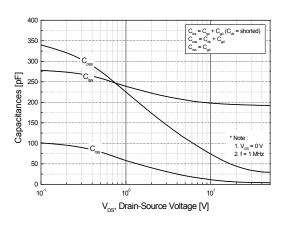
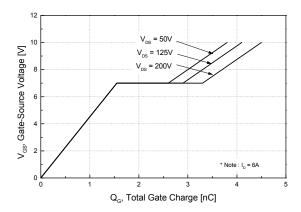


Figure 5. Capacitance Characteristics



Notes:
1. \( \text{V}\_{cs} = 0V \)
2. \( \text{250}\_{LB} = \text{Pulse Test} \)
V<sub>SD</sub>, Source-Drain voltage [V]

Figure 6. Gate Charge Characteristics



### **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

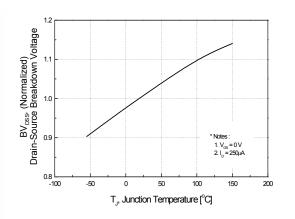


Figure 8. On-Resistance Variation vs. Temperature

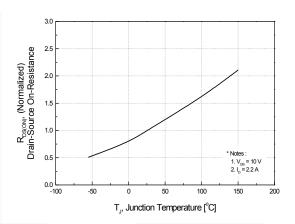


Figure 9. Maximum Safe Operating Area

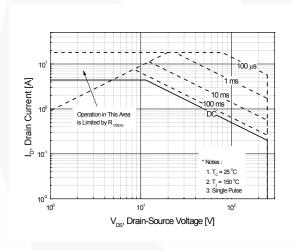


Figure 10. Maximum Drain Current vs. Case Temperature

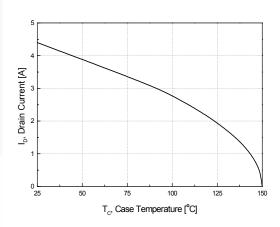
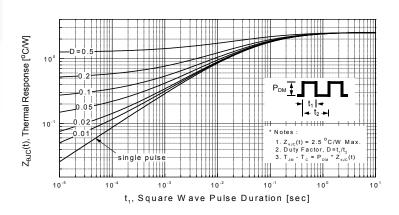


Figure 11. Transient Thermal Response Curve



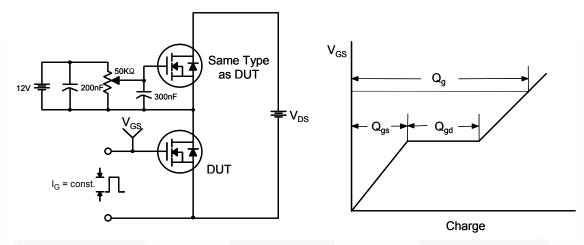


Figure 12. Gate Charge Test Circuit & Waveform

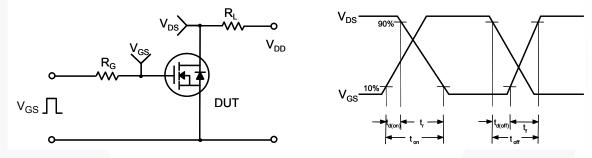


Figure 13. Resistive Switching Test Circuit & Waveforms

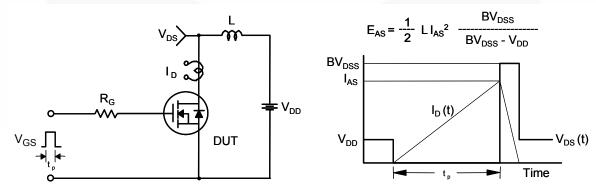


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

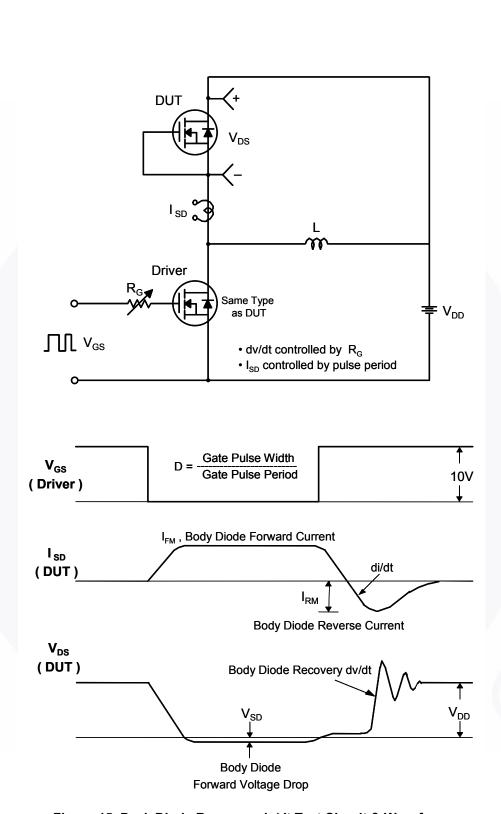


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

#### **Mechanical Dimensions**

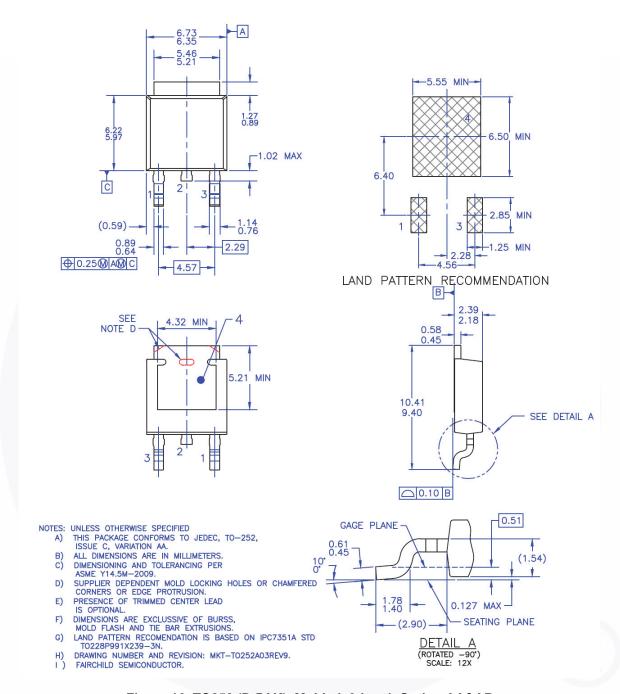


Figure 16. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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